

Technical Data Data Sheet N1117, Rev. - **Green Products**

MBRD660 SCHOTTKY RECTIFIER

Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features:

- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In Inches / mm



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	2.200	2.380	0.087	0.094	
A1	0.000	0.100	0.000	0.004	
b	0.710	0.810	0.028	0.032	
c	0.460	0.560	0.018	0.022	
D	6.500	6.700	0.256	0.264	
D1	5.130	5.460	0.202	0.215	
D2	4.830	REF.	0.190 REF.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	REF.	0.114 REF.		
L2	1.400	1.700	0.055	0.067	
L3	1.600	REF.	0.063	REF.	
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
A2	0.910	1.110	0.036	0.044	
V	5.350 REF.		0.211 REF.		
D3	1.778REF.		0.070REF.		
h	0.762	0.762REF. 0.030REF.		REF.	
0 1	7°		7°		

DPAK





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Marking Diagram:



Where XXXXX is YYWWL

MBR	= Device Type
D	= Package type
6	= Forward Current (6A)
60	= Reverse Voltage (60V)
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRD660	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	60	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =85°C, rectangular wave form	6	A
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	125	А



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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 6A, Pulse, T _J = 25 °C	0.75	V
	V _{F1}	@ 6A, Pulse, T _J = 125 °C	0.70	V
Max. Reverse Current at DC condition	I _{R1}	$@V_R = rated V_R$ T _J = 25 °C	1	mA
Max. Reverse Current	I _{R2}	$@V_R = rated V_R$ T _J = 125 °C	10	mA
Max. Junction Capacitance	CT	@V _R = 5.0V, T _C = 25 °C f _{SIG} = 1MHz	400	pF
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature Range	TJ	-	-55 to +150	°C
Storage Temperature Range	T _{stg}	-	-55 to +150	°C
Maximum Thermal	R _{0JC}	DC operation	6.0	°C/W
Resistance Junction to Case				
Approximate Weight	wt	-	0.39	g
Case Style		DPAK		



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Fig.2-Typical Reverse Characteristics



Fig.3-Typical Instantaneous Forward Voltage Characteristics

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